

## Features

- Single chip synthesised tuner solution for quadrature down conversion, L-band to Zero IF.
- DVB compliant, operating dynamic range -70 to -20dBm.
- Compatible with DSS and DVB variable symbol rate applications.
- Selectable baseband path, programmable through I<sup>2</sup>C bus.
- Excellent quadrature balance up to 30MHz baseband
- Excellent immunity to spurious second harmonic (RF and LO) mixing effects.
- Low oscillator phase noise and reradiation.
- High output referred linearity for low distortion and multi channel application.
- Integral fast mode compliant I<sup>2</sup>C bus controlled PLL frequency synthesiser, designed for high comparison frequencies and low phase noise performance.
- Buffered crystal output for clocking QPSK demodulator.
- ESD protection (Normal ESD handling procedures should be observed).

## Applications

- Satellite receiver systems.
- Data communications systems.

## Ordering Information

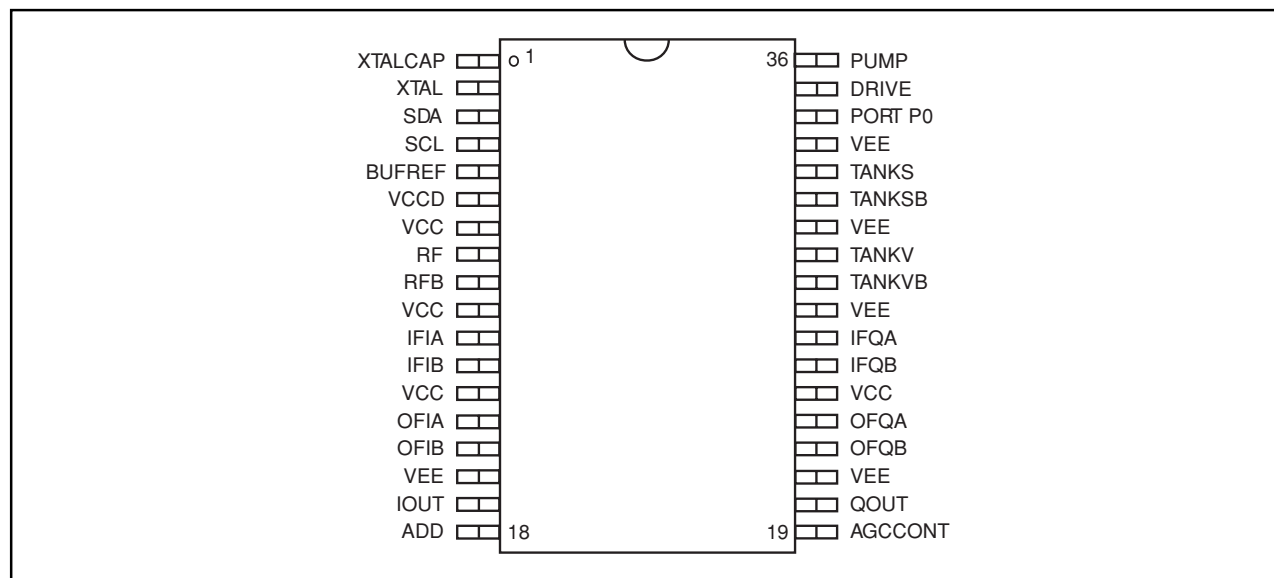
SL1935D/KG/NP1P (Tubes) 36 pin SSOP  
 SL1935D/KG/NP1Q (Tape and Reel) 36 pin SSOP

## Description

The SL1935 is a complete single chip I<sup>2</sup>C bus controlled Zero IF tuner and operates from 950 to 2150MHz. It includes an on-board low phase noise PLL frequency synthesiser and low noise LNA/AGC. The SL1935 is intended primarily for application in digital satellite Network Interface Modules and performs the complete tuner function.

The device contains all elements necessary, with the exception of local oscillator tuning network and crystal reference, to produce a high performance I(n-phase) & Q(uadrature) downconversion tuner function. Due to the high signal handling design the device does not require any front end tracking filters.

The SL1935 includes selectable baseband signal paths, allowing application with two externally definable filter bandwidths, facilitating application in variable symbol rate and simulcast systems. The SL1935 is optimised to interface with the VP310 (ADC/QPSK/FEC) Satellite Channel Decoder, available from Zarlink Semiconductor and offers a full front end solution.



**Figure1. Pin connections**

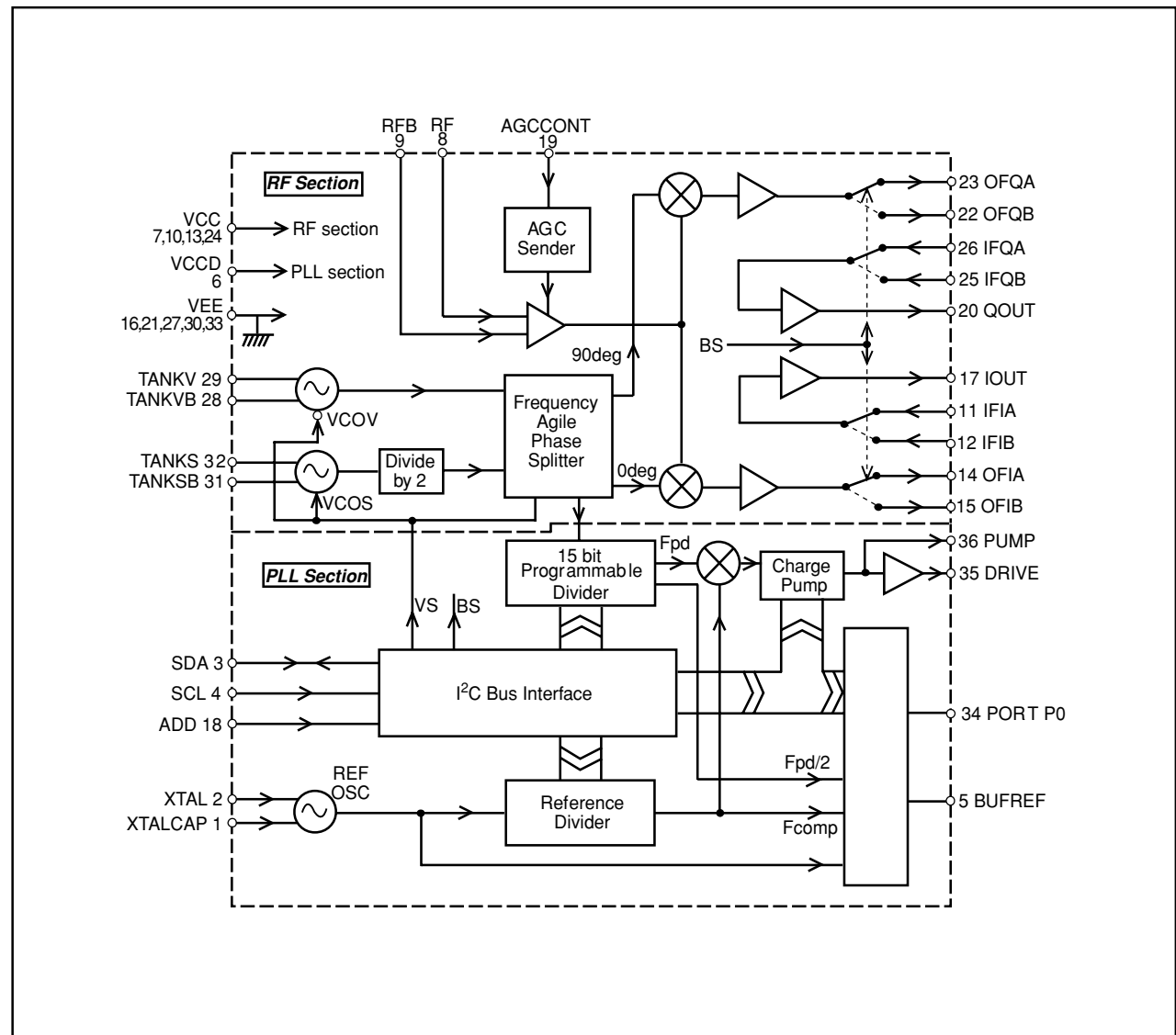


Figure 2. Block diagram

**Table 1. QuickReferenceData**

Characteristic	Value	Units
Operating range	950 to 2150	MHz
Input dynamic range	-75 to -15	dBm
VSWR with input match	10	dB
Input NF		
@ -70dBm operating sensitivity	10	dB
@ -60dBm operating sensitivity	15	dB
IIP3 @ -20dBm operating sensitivity	+5	dBm
IIP2@ -20dBm operating sensitivity	+20	dBm
IPP1dB@ -20dBm operating sensitivity	-5	dBm
Baseband output limit voltage	2.0	V
Gain match up to 22MHz	0.2	dB
Phase match up to 22MHz	0.7	deg
Gain flatness up to 30MHz	1	dB
Local oscillator phase noise		
SSB at 10kHz offset	-80	dBc/Hz
In band LO reradiation from RF input	<-70	dBm
LO second harmonic interference level at input level of -20dBm per carrier	-55	dBc
LNA second harmonic interference level at input level of -25dBm per carrier	-35	dBc
PLL maximum comparison frequency	4	MHz
PLL phase noise at phase detector	-152	dBc/Hz

Note:  $\infty$ 6dB interstage filter loss assumed in external base band paths.  
 $\infty$ dBm assumes 75 $\Omega$  characteristic impedance.

## Functional Description

### General

The SL1935 is a complete wideband direct conversion tuner incorporating an on board frequency synthesiser and LNA/AGC, optimised for application in digital satellite receiver systems. The device offers a highly integrated solution to a satellite tuner function, incorporating an I<sup>2</sup>C bus interface controller, a low phase noise PLL frequency synthesiser and all tuner analogue functionality. The analogue blocks include the reference oscillator, consisting of two independent oscillators, a phase splitter, RF preamplifier with AGC facility, channel mixers and baseband amplifiers incorporating two selectable baseband paths, allowing for two externally definable bandwidths. In this application two varactor tuned tanks, a reference crystal and baseband filtering components are required to complete the tuner system.

A buffered crystal frequency output is available to clock the QPSK demodulator and powers up in the active state.

The I<sup>2</sup>C bus interface controls the frequency synthesiser, the local oscillator, the baseband path selection, the buffered reference frequency output and an external switching port.

Figure 2 shows the device block diagram and pin allocations are shown in Figure 1.

### Quadrature Downconverter Section

In normal application the tuner IF frequency of typically 950 to 2150MHz is fed direct to the SL1935 RF input through an appropriate impedance match (Fig.16) and LNB switching. The input stage is optimised for both NF and signal handling.

The signal handling of the front end is designed to offer immunity to input composite overload without the requirement of a tracking filter. RF input impedance is shown in Fig.3.

The RF input amplifier feeds an AGC stage and provides system gain control. The system AGC gain range will guarantee an operating dynamic range of -70 to -20dBm. The AGC is controlled by the AGC sender and is optimised for S/N and S/I performance across the full dynamic range. Details of the AGC characteristics, variations in IIP3, IIP2, P1dB and NF are illustrated in Figs.4, 5, 6, 7, and 8 respectively.

The required I and Q local oscillator frequencies for quadrature downconversion are generated by the on-board reference oscillators designated 'VCOS' and 'VCOV'. VCOS operates nominally from 1900 to 3000MHz and is then divided by two to provide 950 to 1500MHz. VCOV operates nominally from 1400 to 2200MHz. Only the oscillator selected via bit VS in the I<sup>2</sup>C data transmission is powered.

### Quadrature Downconverter Section - continued

The oscillators share a common varactor line drive and both require an external varactor tuned resonator optimised for low phase noise performance. The recommended application circuit for the local oscillators is detailed in Fig.9 and the typical phase noise performance is detailed in Fig.10. The local oscillator frequency is coupled internally to the PLL frequency synthesiser programmable divider input.

The mixer outputs are coupled to the baseband buffer amplifiers, providing for one of two selectable baseband outputs in each channel. The required output is selected by bit BS in the I<sup>2</sup>C bus transmission (Table 6). These outputs are fed off chip via ports 'OPIA' and 'OPIB' ('OPQA' and 'OPQB'), then back on chip through ports 'IPIA' and 'IPIB' ('IPQA' and 'IPQB'), allowing for the insertion of two independent user definable filter bandwidths. Each output provides a low impedance drive (Fig.11) and each input provides a high impedance load. An example filter for 30MS/s is detailed in Fig.13. Both path gains are nominally equal. NB 6dB insertion loss is assumed in each channel, however a different pot down ratio may be applied.

Each baseband path is then multiplexed to the final baseband amplifier stage, providing further gain and a low impedance output drive. The nominal output load test condition is detailed in Fig.14.

### PLL Frequency Synthesiser Section

The PLL frequency synthesiser section contains all the elements necessary, with the exception of a reference frequency source and a loop filter to control the selected oscillator to produce a complete PLL frequency synthesised source. The device, produced using high speed logic, allows for operation with a high comparison frequency and enables the generation of a loop with excellent phase noise performance.

The LO signal from the selected oscillator drives from the phase splitter into an internal preamplifier, providing gain and reverse isolation from the divider signals. The output of the preamplifier interfaces directly with the 15-bit fully programmable divider. The programmable divider has MN+A architecture, the dual modulus prescaler is 16/17, the A counter is 4-bits and the M counter is 11-bits.

The output of the programmable divider is fed to the phase comparator and compared in both phase and frequency domains to the comparison frequency. This frequency is derived from either the on board crystal controlled oscillator or from an external reference source. In both cases the reference frequency is divided down to the comparison frequency by the reference divider, programmable into 1 of 29 ratios and detailed in Table 3. The typical application for the crystal oscillator is shown in Fig.15.

The output of the phase detector feeds a charge pump and a loop amplifier. When used with an external loop filter and a high voltage transistor it integrates the current pulses into the varactor line voltage used to control the selected oscillator.

The programmable divider output Fpd divided by two and the reference divider output Fcomp are switched to port P0 by programming the device into test mode. Test modes are detailed in Table 4.

The crystal reference frequency can be switched to the BUFREF output by bit RE as detailed in Table 7.

## Programming

The SL1935 is controlled by an I<sup>2</sup>C data bus and is compatible with both standard and fast mode formats. Data and Clock are fed on the SDA and SCL lines respectively as defined by the I<sup>2</sup>C bus format. The device can either accept data (write mode) or send data (read mode). The LSB of the address byte (R/W) sets the device into write mode if it is low and read mode if it is high. Tables 9a and 9b detail the format of the data. The SL1935 may be programmed to respond to several addresses and enables the use of more than one device in an I<sup>2</sup>C bus system. Table 9c details the how the address is selected by applying a voltage to the 'ADD' input. When the device receives a valid address byte, it pulls the SDA line low during the acknowledge period and during following acknowledge periods after further data bytes are received. When the device is programmed into read mode, the controller accepting the data must pull the SDA line low during all status byte acknowledge periods to read another status byte. If the controller fails to pull the SDA line low during this period, the device generates an internal 'STOP' condition which inhibits further reading.

### Write mode

Bytes 2 and 3 contain frequency information bits 2<sup>14</sup> to 2<sup>0</sup> inclusive (Table 9). Byte 4 controls the synthesiser reference divider ratio (Table 3) and the charge pump setting (Table 5). Byte 5 controls test modes (Table 4), baseband filter path select BS (Table 6), local oscillator select VS (Table 8), buffered crystal reference output select RE (Table 7) and the output port P0.

After reception and acknowledgment of a correct address (byte 1), the first bit of the following byte determines whether the byte is interpreted as byte 2 or 4, a logic '0' indicates byte 2 and a logic '1' indicates byte 4. Having interpreted this byte as either byte 2 or 4, the following byte will be interpreted as byte 3 or 5 respectively. After receiving two complete data bytes, additional data bytes may be entered and byte interpretation follows the same procedure without re-addressing the device. The procedure continues until a 'STOP' condition is received.

The STOP condition can be generated after any data byte, if however it occurs during a byte transmission, the previous byte data is retained. To facilitate smooth fine tuning, the frequency data bytes are only accepted by the device after all 15 bits of frequency data have been received, or after the generation of a STOP condition.

### Read mode

When the device is in read mode, the status byte read from the device takes the form shown in Table 9b.

Bit 1 (POR) is the power-on reset indicator, and this is set to a logic '1' if the V<sub>cc</sub> supply to the device has dropped below 3V (at 25°C), e.g. when the device is initially turned ON. The POR is reset to '0' when the read sequence is terminated by a STOP command. When POR is set high this indicates that the programmed information may have been corrupted and the device reset to the power up condition.

Bit 2 (FL) indicates whether the synthesiser is phase locked, a logic '1' is present if the device is locked, and a logic '0' if the device is unlocked.

**Table 2. Programmable Features**

Programmable features	Function
Synthesiser programmable divider	Function as described above
Reference programmable divider	Function as described above.
Baseband filter path select	Function as described above.
Local oscillator select	Function as described above.
Charge pump current	The charge pump current can be programmed by bits C1 & C0 (Table 5).
Test mode	The test modes are defined by bits T2 - T0 as described in Table 4.
General purpose port, P0	The general purpose port can be programmed by bit P0; Logic '1' = on Logic '0' = off (high impedance)
Buffered crystal reference output, BUFREF	The buffered crystal reference frequency can be switched to the BUFREF output by bit RE as described in Table 7. The BUFREF output defaults to the 'ON' condition at device power up.

The typical key performance data at V<sub>cc</sub> = 5V and +25°C ambient are detailed in Table 1.

**Table 3. Reference division ratios**

R4	R3	R2	R1	R0	Ratio
0	0	0	0	0	2
0	0	0	0	1	4
0	0	0	1	0	8
0	0	0	1	1	16
0	0	1	0	0	32
0	0	1	0	1	64
0	0	1	1	0	128
0	0	1	1	1	256
0	1	0	0	0	Illegal state
0	1	0	0	1	5
0	1	0	1	0	10
0	1	0	1	1	20
0	1	1	0	0	40
0	1	1	0	1	80
0	1	1	1	0	160
0	1	1	1	1	320
1	0	0	0	0	Illegal state
1	0	0	0	1	6
1	0	0	1	0	12
1	0	0	1	1	24
1	0	1	0	0	48
1	0	1	0	1	96
1	0	1	1	0	192
1	0	1	1	1	384
1	1	0	0	0	Illegal state
1	1	0	0	1	7
1	1	0	1	0	14
1	1	0	1	1	28
1	1	1	0	0	56
1	1	1	0	1	112
1	1	1	1	0	224
1	1	1	1	1	448

**Table 4. Test modes**

T2	T1	T0	Test mode description
0	0	0	Normal operation
0	0	1	Charge pump sink* (status byte FL set to logic '0')
0	1	0	Charge pump source* (status byte FL set to logic '0')
0	1	1	Charge pump disabled* (status byte FL set to logic '1')
1	0	0	Normal operation and port P0 = Fpd/2
1	0	1	Charge pump sink* (status byte FL set to logic '0'. Port P0 = Fcomp)
1	1	0	Charge pump source* (status byte FL set to logic '0'. Port P0 = Fcomp)
1	1	1	Charge pump disabled* (status byte FL set to logic '1'. Port P0 = Fcomp)

Note: \* Clocks need to be present on crystal and RF inputs to enable charge pump test modes and to toggle status byte bit FL.

**Table 5. Charge pump current**

C1	C0	Current in $\mu\text{A}$		
		min	typ	max
0	0	+/-116	+/-155	+/-194
0	1	+/-247	+/-330	+/-412
1	0	+/-517	+/-690	+/-862
1	1	+/-1087	+/-1450	+/-1812

**Table 6. Baseband path select**

BS	Path Selected			
	I Channel		Q Channel	
	Filter drive output	Baseband amp input	Filter drive output	Baseband amp input
0	OFIB	IFIB	OFQB	IFQB
1	OFIA	IFIA	OFQA	IFQA

**Table 7. Buffered crystal reference output select**

RE	BUFREF output
0	Disabled, high impedance
1	Enabled

**Table 8. Local oscillator select**

VS	Local oscillator selected
0	VCOV
1	VCOS

**Table 9a. Write data format (MSB is transmitted first)**

	MSB							LSB		
Address	1	1	0	0	0	MA1	MA0	0	A	Byte 1
Programmable divider	0	$2^{14}$	$2^{13}$	$2^{12}$	$2^{11}$	$2^{10}$	$2^9$	$2^8$	A	Byte 2
Programmable divider	$2^7$	$2^6$	$2^5$	$2^4$	$2^3$	$2^2$	$2^1$	$2^0$	A	Byte 3
Control data	1	C1	C0	R4	R3	R2	R1	R0	A	Byte 4
Control data	T2	T1	T0	VS	BS	0	RE	P0	A	Byte 5

**Table 9b. Read data format (MSB is transmitted first)**

	MSB							LSB		
Address	1	1	0	0	0	MA1	MA0	1	A	Byte 1
Status Byte	POR	FL	0	0	0	0	0	0	A	Byte 2

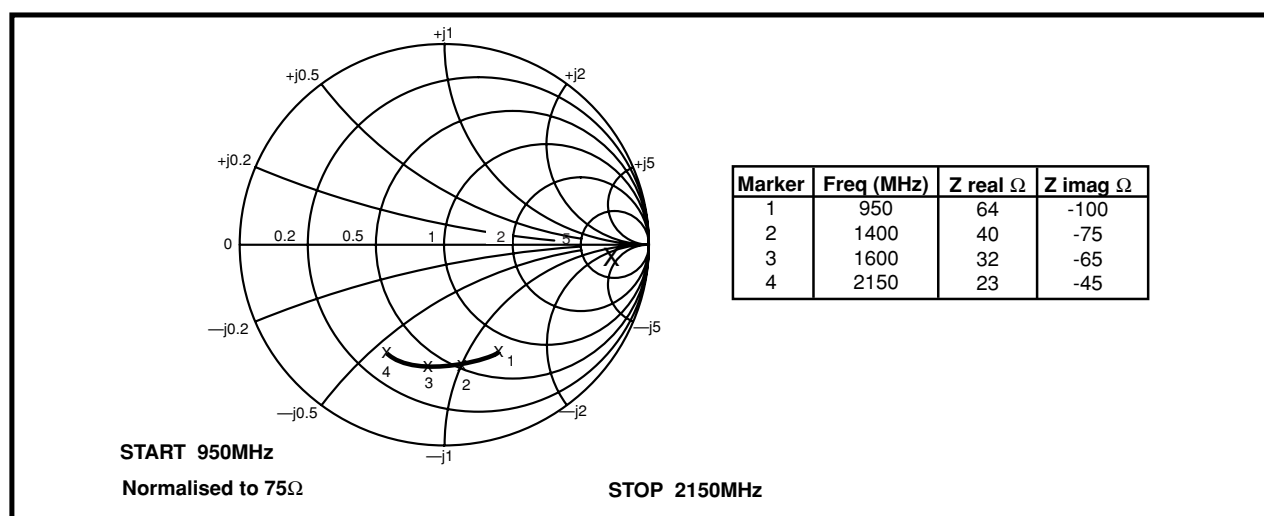
**Table 9c. Address selection**

MA1	MA0	Address input voltage level
0	0	0 - 0.1 Vcc
0	1	Open circuit
1	0	0.4 Vcc - 0.6 Vcc*
1	1	0.9 Vcc - Vcc

Note: \* Programmed by connecting a 30k $\Omega$  resistor between pin and Vcc

**Key to Tables 9a to 9c**

A ..... Acknowledge bit  
 MA1, MA0 ..... Variable address bits (Table 9c)  
 $2^{14}$  to  $2^0$  ..... Programmable division ratio control bits  
 C1 to C0 ..... Charge pump current select (Table 5)  
 R4 to R0 ..... Reference division ratio select (Table 3)  
 T2 to T0 ..... Test modes control bits (Table 4)  
 BS ..... Baseband path select (Table 6)  
 VS ..... Local oscillator select (Table 8)  
 RE ..... Buffered crystal reference output enable (Table 7)  
 P0 ..... P0 port output state  
 POR ..... Power on reset indicator  
 FL ..... Phase lock flag

**Figure 3. RF input impedance (typical)**

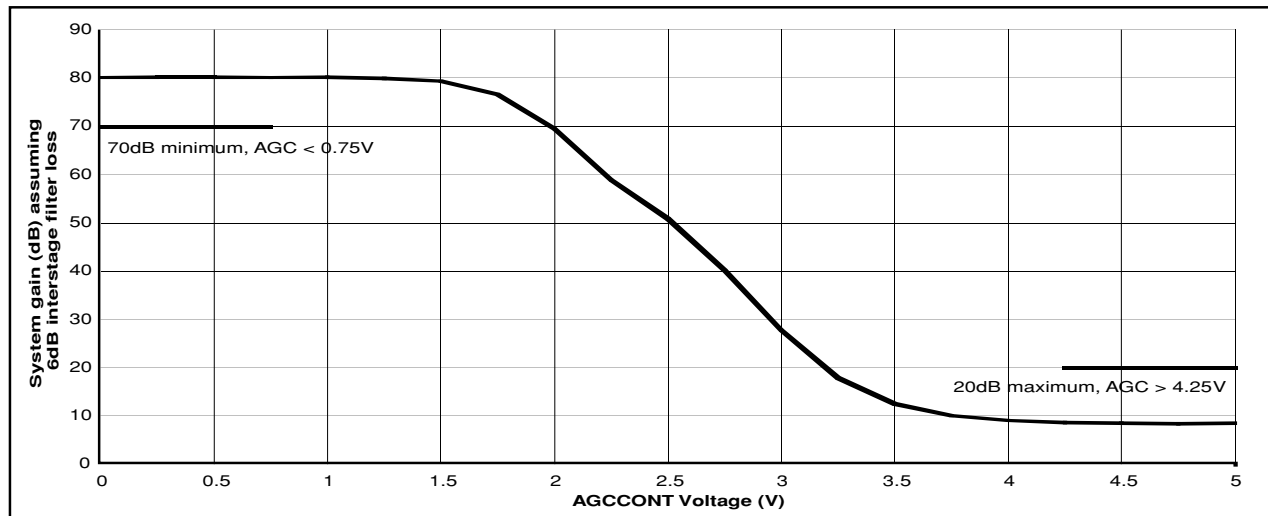


Figure 4. AGC characteristic (typical)

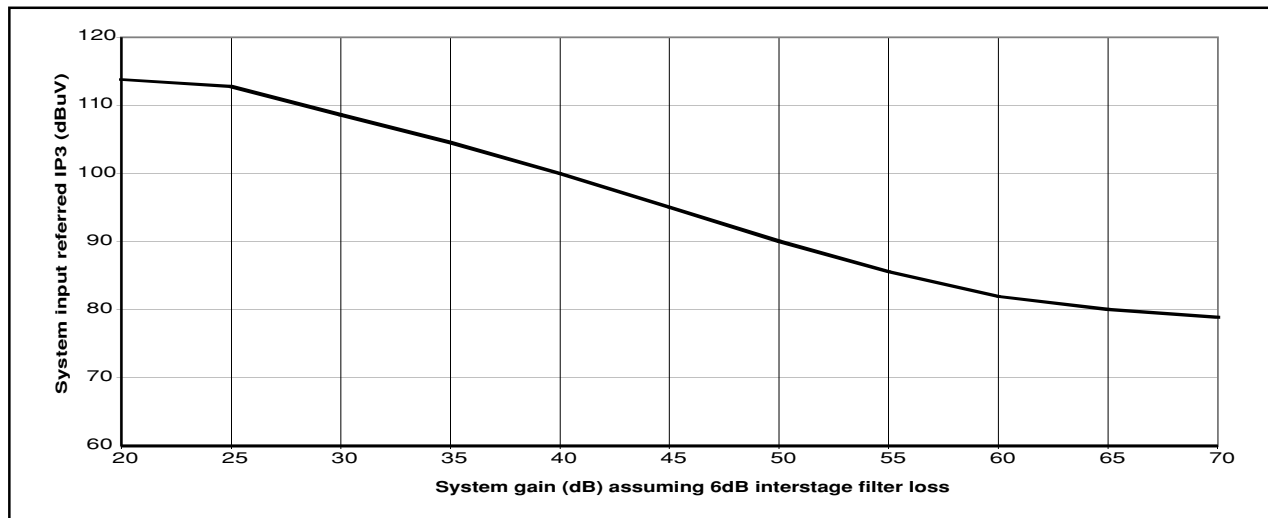


Figure 5. Variation in IIP3 with system gain (typical)

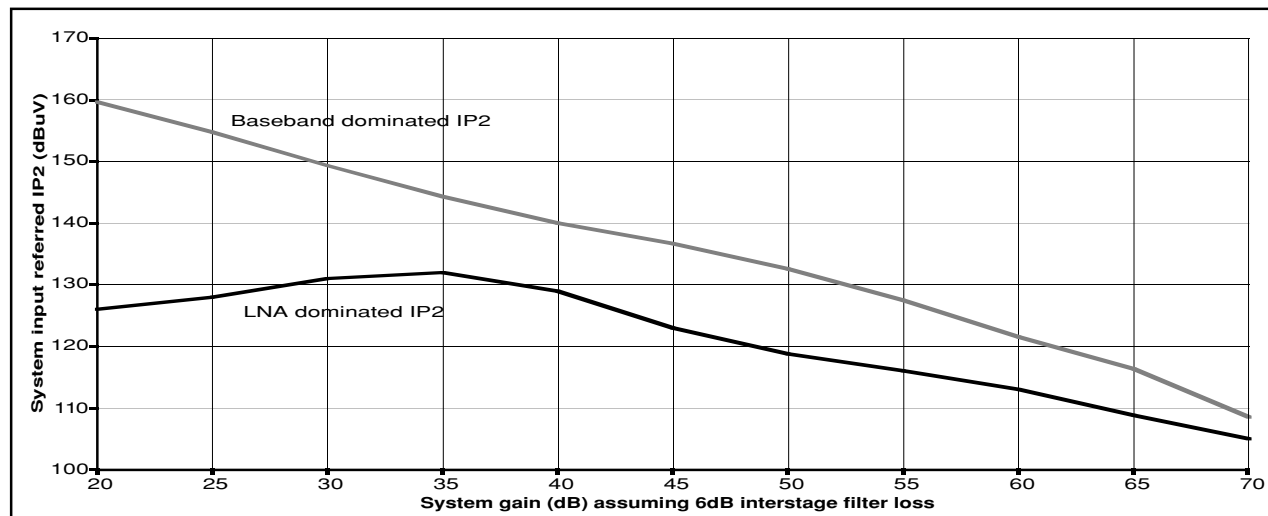


Figure 6. Variation in IIP2 with system gain (typical)



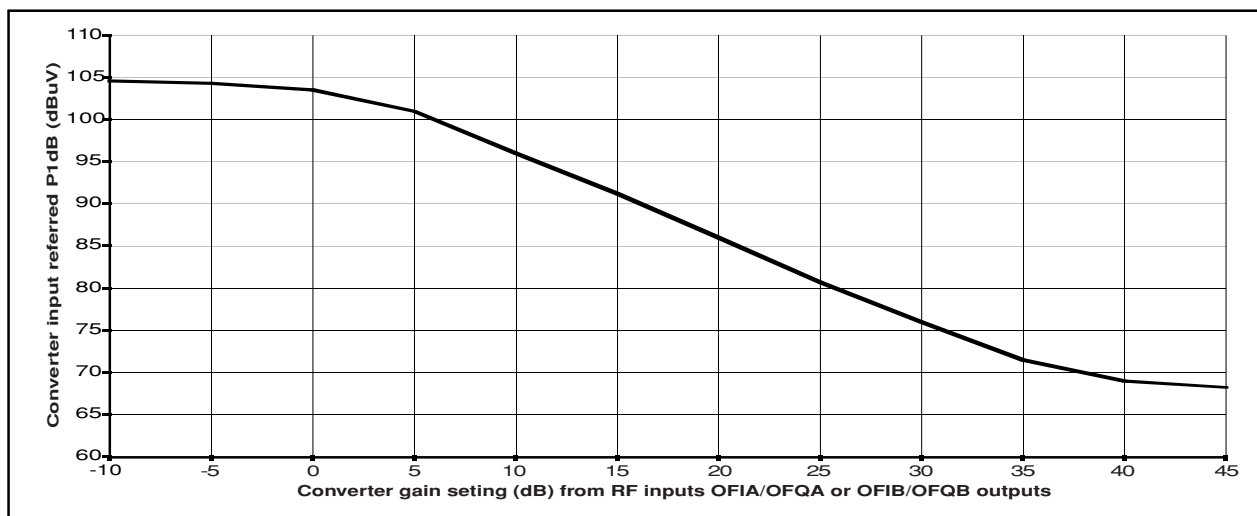


Figure 7. Variation in P1dB with converter gain (typical)

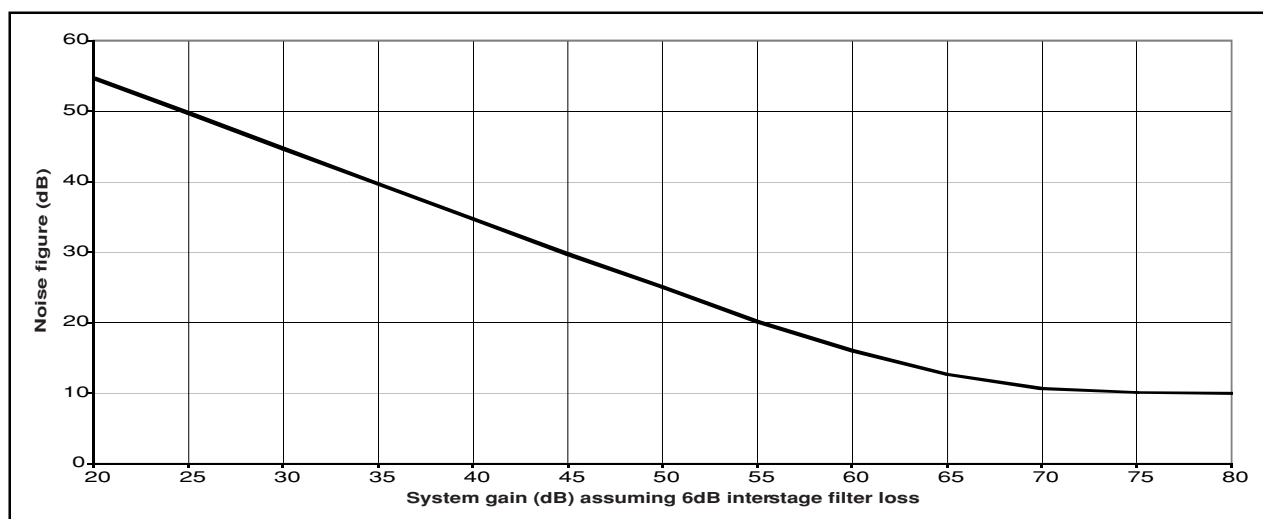


Figure 8. Variation in NF with system gain (typical)

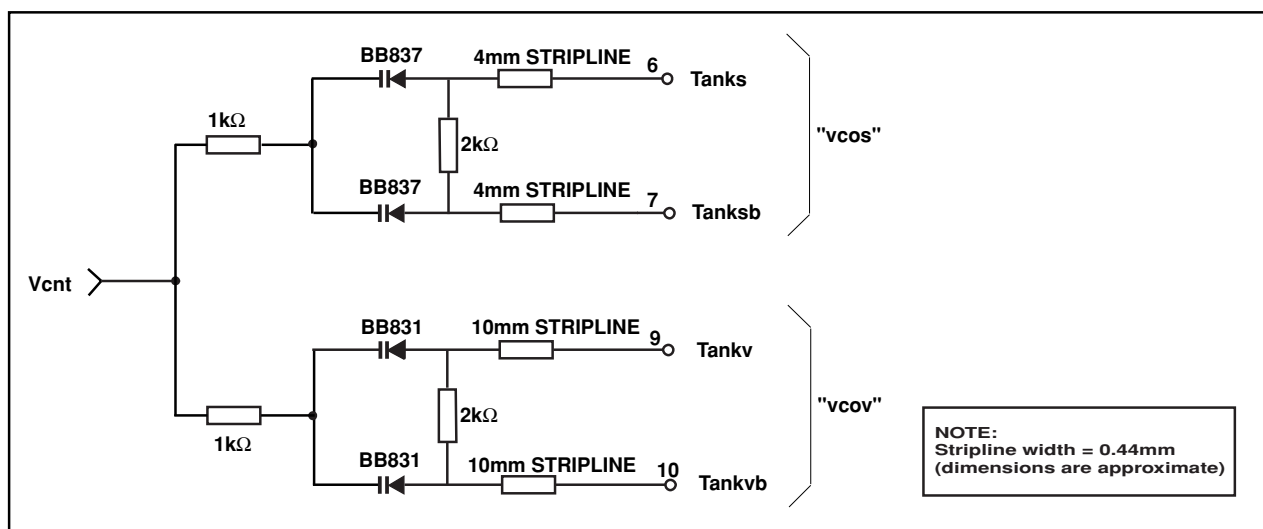


Figure 9. Local oscillator application circuit

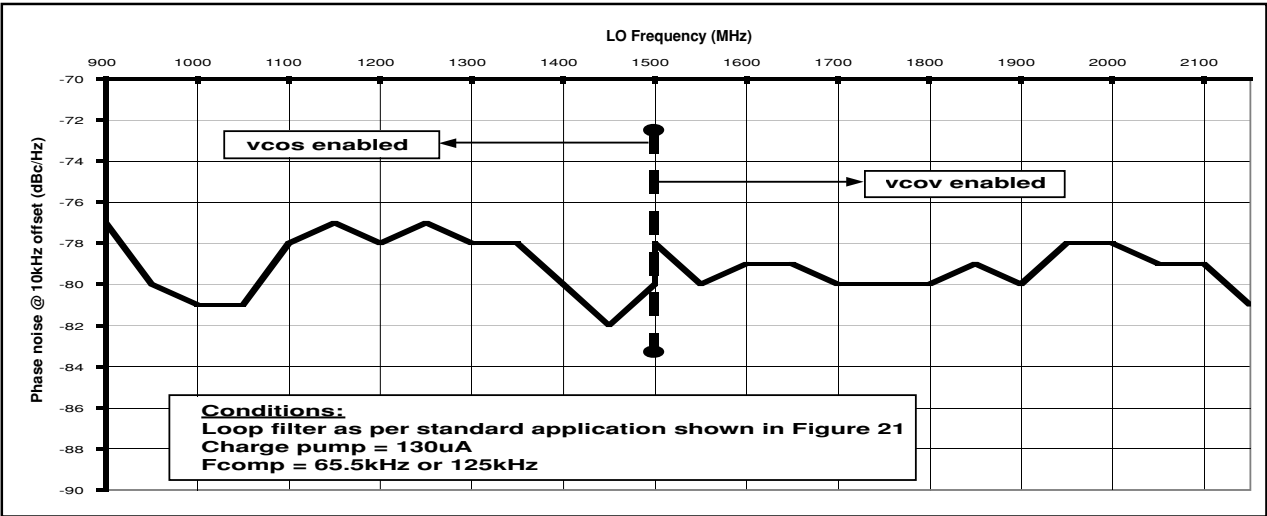


Figure 10. Local oscillator phase noise variation with frequency (typical)

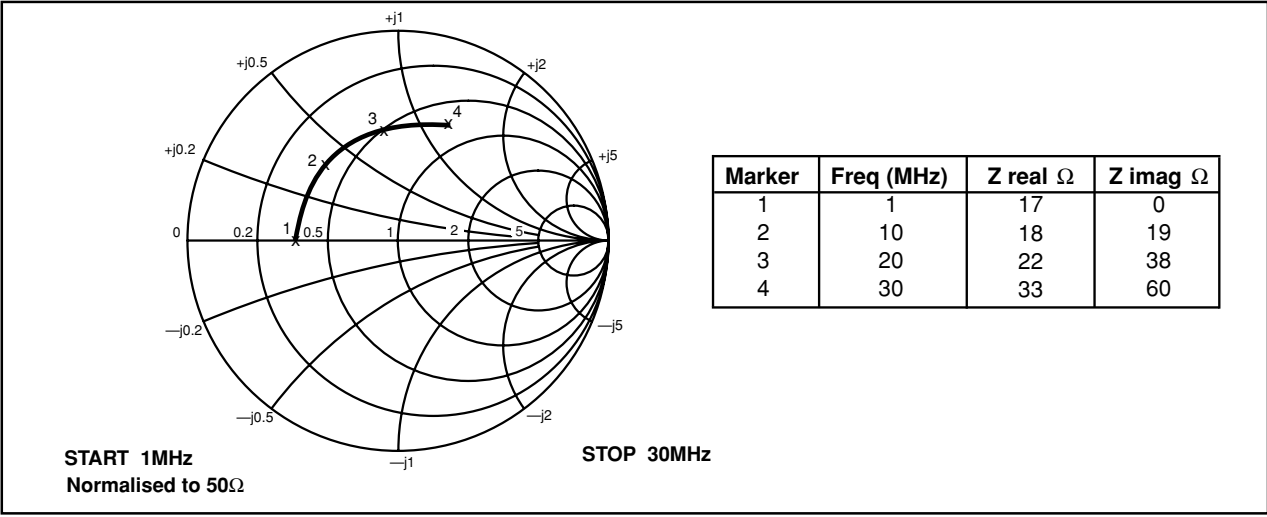


Figure 11. Converter output impedance; OFIA, OFIB, OFQA, OFQB (typical)

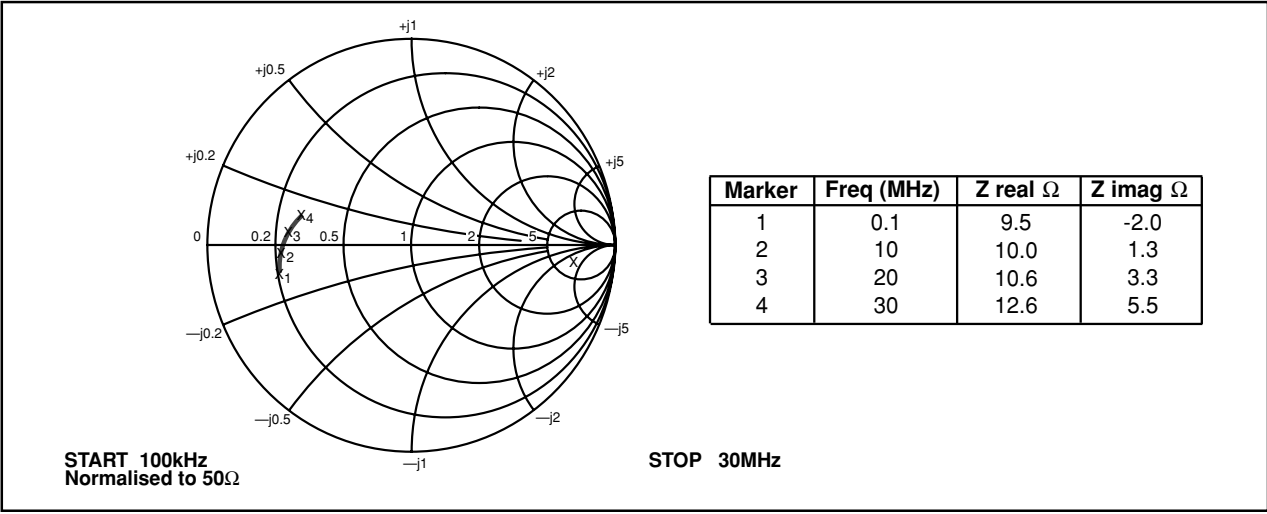


Figure 12. Baseband output impedance; IOU, QOUT (typical)

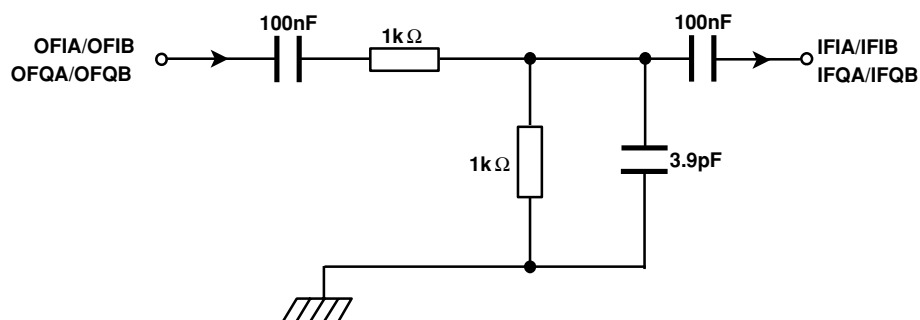


Figure 13. Example baseband interstage filter for 30MS/s

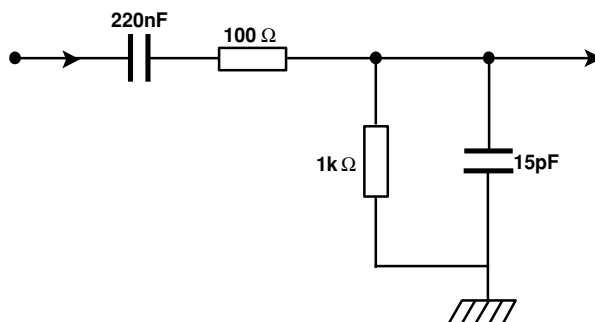


Figure 14. Nominal baseband output load test condition

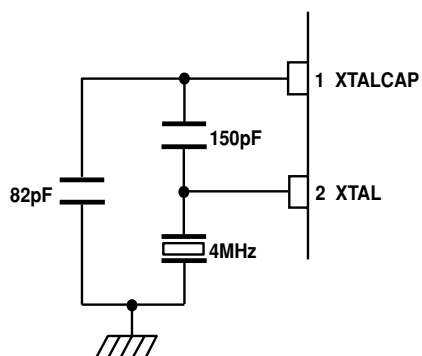


Figure 15. Crystal oscillator application (typical)

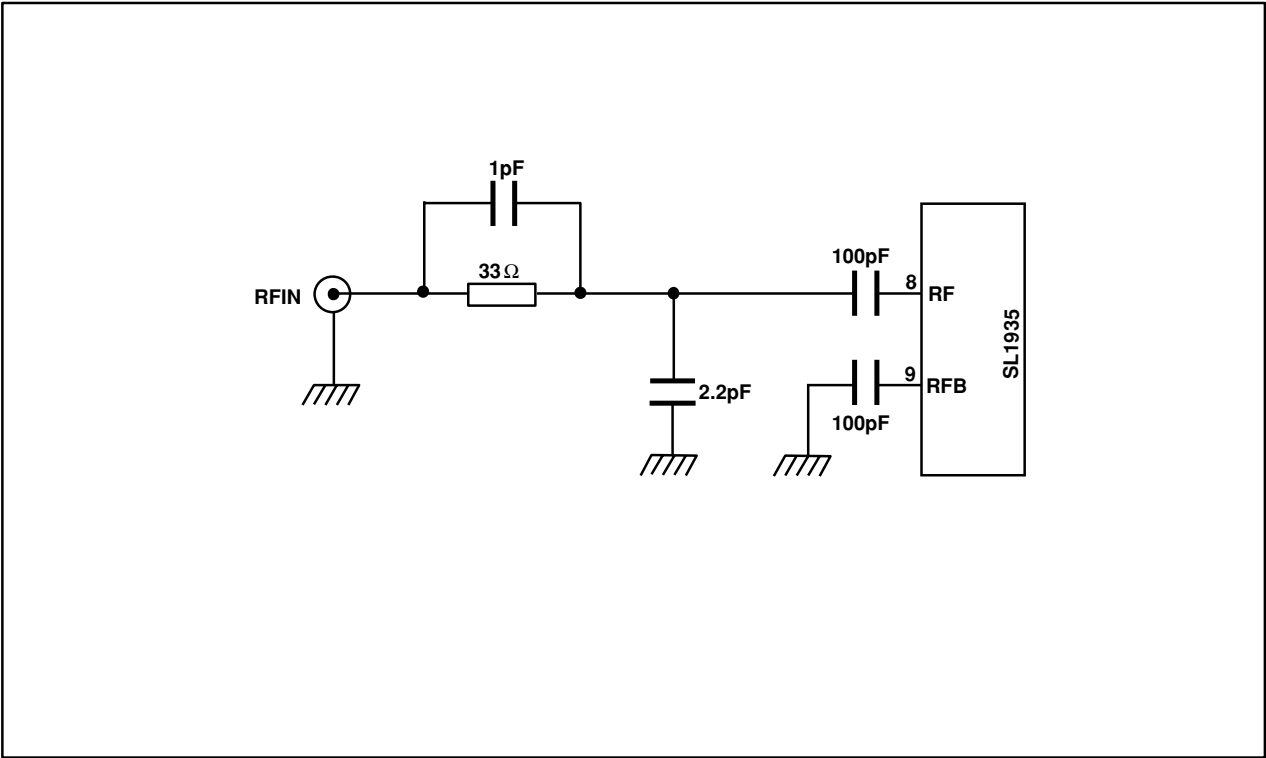


Figure 16. Input matching network

Table 10. Electrical Characteristics

Test conditions (unless otherwise stated); Tamb = -20<sup>o</sup>to +80<sup>o</sup>C, Vee= 0V, Vcc =Vccd = 5V+-5%.  
These characteristics are guaranteed by either production test or design. They apply within the specified ambient temperature and supply voltage unless otherwise stated.

Characteristic	Pin	Value			Units	Conditions
		Min	Typ	Max		
Supply current	6,7,10 13,24		130	175	mA	VCCD (PLL) and VCC
RF input operating frequency	8,9	950		2150	MHz	
<b>SYSTEM</b>						
System noise figure DSB			10 15	12 17	dB dB	All system specification items should be read in conjunction with Note 2 At -70dBm operating sensitivity At -60dBm operating sensitivity Above -60dBm operating sensitivity, (Fig.7) At -20dBm operating sensitivity, see Notes 3 and 4 (Fig.6) At -20dBm operating sensitivity, see Note 5 (Fig.5)
Variation in system NF with gain adjust				-1	dB/dB	
System input referred IP2		121	140		dBμV	
Variation in system input referred IP2 with operating sensitivity						
System input referred IP3		112			dBμV	
Variation in system input referred IP3 with operating sensitivity						

Continued

**Table 10. Electrical Characteristics** (Continued)

Characteristic	Pin	Value			Units	Conditions
		Min	Typ	Max		
System dynamic range		-70		-20	dBm dBm	Note 6 AGCCONT = 0.75V AGCCONT = 4.25V
System gain roll off			3		dB	Within RF band 950-2150MHz
System gain variation with temperature			2		dB	-20°C to +80°C
System I Q gain match	17,20	-1		+1	dB	Interstage filter (Fig.13)
System I Q phase balance	17,20	-3		+3	deg	Interstage filter (Fig.13)
System I and Q channel in band ripple	17,20			1	dB	Interstage filter (Fig.13)
System baseband path gain match		-1		+1	dB	
LO second harmonic interference level			-50		dBc	Note 8.
LNA second harmonic interference level			-35		dBc	Note 9.
Synthesiser and other spuri on I and Q outputs	17,20			76	dBμV	Within 0-100MHz band under all gain settings, RF input set to deliver 108dBμV on output
In band leakage to RF input	8,9		-60		dBm	Within RF band 950-2150MHz. Note 11.
<b>CONVERTER</b>						
Converter input impedance	8,9		75		Ω	
Converter input return loss	8,9	8			dB	With input matching (Fig.16)
System input referred P1dB		102			dBμV	Converter gain = -5dBm (to OFIA/OPQA, OFIB/OPQB outputs. Fig.7)
Converter output impedance, OFIA, OFIB, OPQA and OPQB.	14,15 22,23		25	50	Ω	0.1 to 30MHz (Fig.11)
Converter output leakage to unselected output, OFIA, OFIB, OPQA and OPQB.			-26		dBc	Relative to selected output
Oscillator VCOS operating range	31,32	1900		3000	MHz	Giving LO = 950 to 1500MHz (Application as in Fig.9)
Oscillator VCOV operating range	28,29	1450		2150	MHz	(Application as in Fig.9)
Local oscillator SSB phase noise			-78		dBc/Hz	@10kHz offset, PLL loop bw < 1kHz Application is measured at baseband output frequency of 10MHz (Fig.10).
AGCONT input current	19	-150		150	μA	
<b>BASEBAND AMPLIFIERS</b>						
Baseband input impedance, IFIA, IFIB, IFQA And IFQB.	11,12 25,26					The baseband inputs must be externally ac coupled 0.1- 30MHz bandwidth
Resistance		10			kΩ	
Capacitance				5	pF	
Baseband unselected input leakage to output	17,20			-40	dBc	Relative to selected input.
Baseband amplifier output impedance	17,20			20	Ω	
Baseband output limiting	17,20		2.0		Vp-p	Level at hard clipping (load as Fig.14)
Baseband bandwidth 1dB	17,20	40			MHz	(Load as Fig.14)
Baseband output roll-off		6			dB/oct	Above 3dB point, no load

Continued

**Table 10. Electrical Characteristics** (Continued)

Characteristic	Pin	Value			Units	Conditions
		Min	Typ	Max		
<b>SYNTHESISER</b>						
SDA,SCL	3,4					I <sup>2</sup> C 'fast mode' compliant
Input high voltage		3		5.5	V	
Input low voltage		0		1.5	V	
Input high current				10	µA	Input voltage = V <sub>cc</sub>
Input low current		-10			µA	Input voltage = V <sub>ee</sub>
Leakage current				10	µA	V <sub>cc</sub> = V <sub>ee</sub> = 0V
Hysteresis			0.4		V	
SDA output voltage	3			0.4	V	I <sub>sink</sub> = 3mA
				0.6	V	I <sub>sink</sub> = 6mA
SCL clock rate	4			400	kHz	
Charge pump output current	36					V <sub>pin36</sub> = 2V. (Table 5)
Charge pump output leakage	36		+ -3	+ -10	nA	V <sub>pin36</sub> = 2V
Charge pump drive output current	35	0.5			mA	V <sub>pin35</sub> = 0.7V
Crystal frequency	1,2	2		20	MHz	(Fig.15 for application)
Recommended crystal series resistance		10		200	Ω	4MHz parallel resonant crystal
External reference input frequency	2	2		20	MHz	Sinewave coupled via 10nF blocking capacitor
External reference drive level	2	0.2		0.5	V <sub>pp</sub>	Sinewave coupled via 10nF blocking capacitor
Phase detector comparison frequency				4	MHz	
Equivalent phase noise at phase detector			-152		dBc/Hz	SSB within loop bandwidth, all comparison frequencies
Local oscillator programmable divider division ratio		240		32767		
Reference division ratio						(Table 3)
Output port P0	34					(Note 7)
Sink current		2			mA	V <sub>port</sub> = 0.7
Leakage current				10	µA	V <sub>port</sub> = V <sub>cc</sub>
BUFREF output	5					AC coupled. (Note 10.)
Output amplitude		0.25	0.35	0.45	V <sub>pp</sub>	Enabled by bit RE = 1 and default state on power-up.
Output impedance			250		Ω	(Table 9c)
Address select	18					
Input high current				1	mA	V <sub>in</sub> = V <sub>cc</sub>
Input low current				-0.5	mA	V <sub>in</sub> = V <sub>ee</sub>

**Notes to Table 10**

1. All power levels are referred to 75Ω, and 0dBm = 109dBµV.
2. System specifications refer to total cascaded system of converter/AGC stage and baseband amplifier stage with nominal 6dB pad as interstage filter and load impedance as detailed in Figure 14.
3. Baseband dominated IP2. AGC set for 20dB system gain with two tones for intermodulation test at fc+146 and fc+155MHz at 100dBµV generating output intermodulation spur at 9MHz. 30MHz 3dB bandwidth interstage filter included.
4. LNA dominated IP2. AGC set for 20dB system gain with two tones for intermodulation test at fc+146 and 2\*fc+155 MHz at 100dBµV generating output intermodulation spur at 9MHz. 30MHz 3dB bandwidth interstage filter included.
5. AGC set for 20dB system gain with two tones for intermodulation test at fc+110 and fc+211MHz at 100dBµV generating output intermodulation spur at 9MHz. 30MHz 3dB bandwidth interstage filter included.
6. Dynamic range assuming termination as detailed in Figure 14, and including 6 dB interstage filter insertion loss, delivering 700mVp-p at baseband outputs (pins 17,20). AGC monotonic from V<sub>ee</sub> to V<sub>cc</sub> (Fig.4).
7. Port powers up in high impedance state.
8. The level of 2.01GHz downconverted to baseband relative to 1.01GHz with the oscillator tuned to 1GHz, measured with no input pre-filtering.
9. The level of second harmonic of 1.01GHz input at -25dBm downconverted to baseband relative to 2.01GHz at -40 dBm with the oscillator tuned to 2GHz, measured with no input pre-filtering.
10. If the BUFREF output is not used it should be left open circuit or connected to V<sub>ccd</sub>, and disabled by setting RE = '0'.
11. This parameter is very application dependant. With good RF isolation <-60dBm can be achieved.

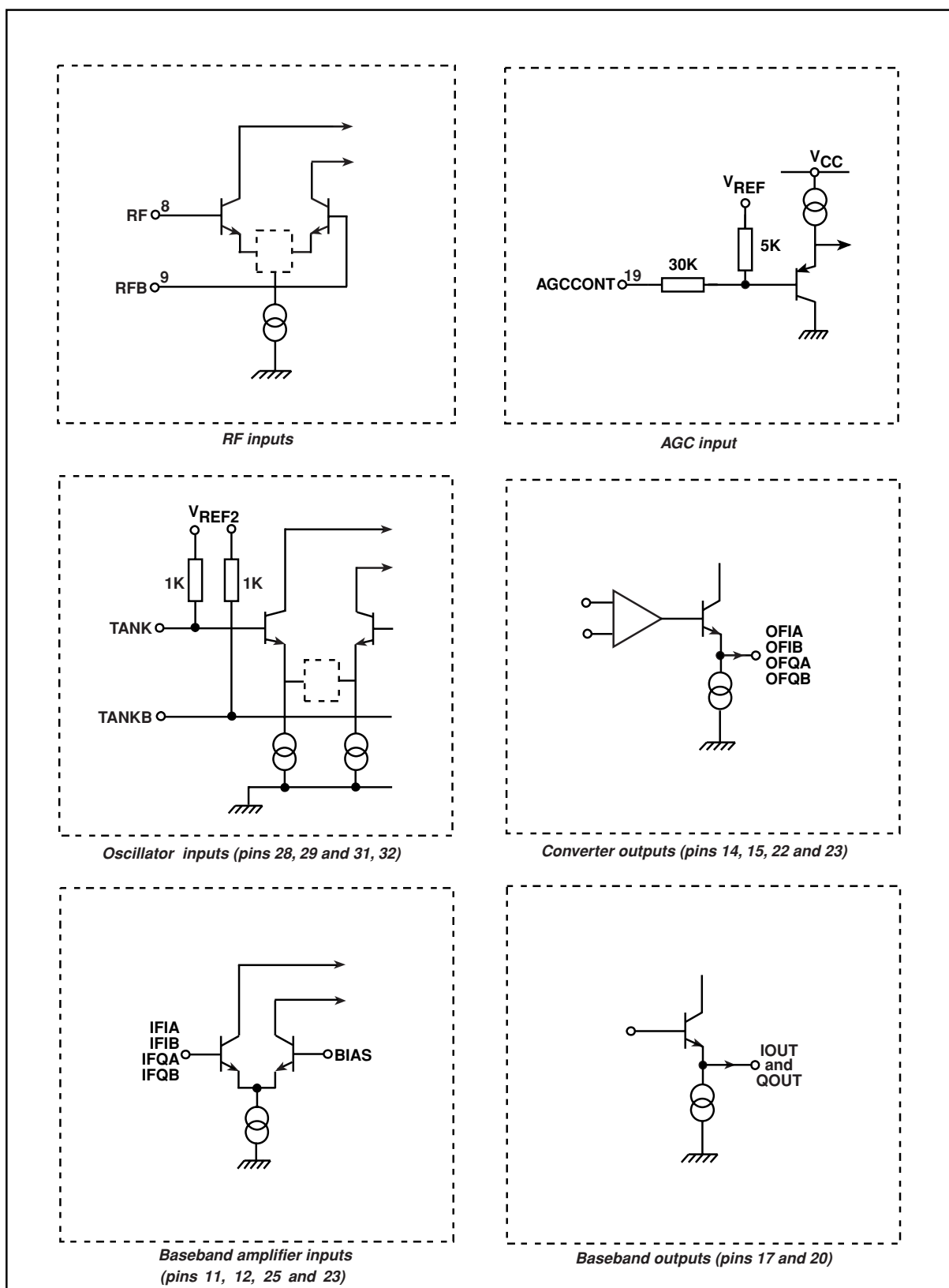


Figure 17. Input and output interface circuits (RF section)

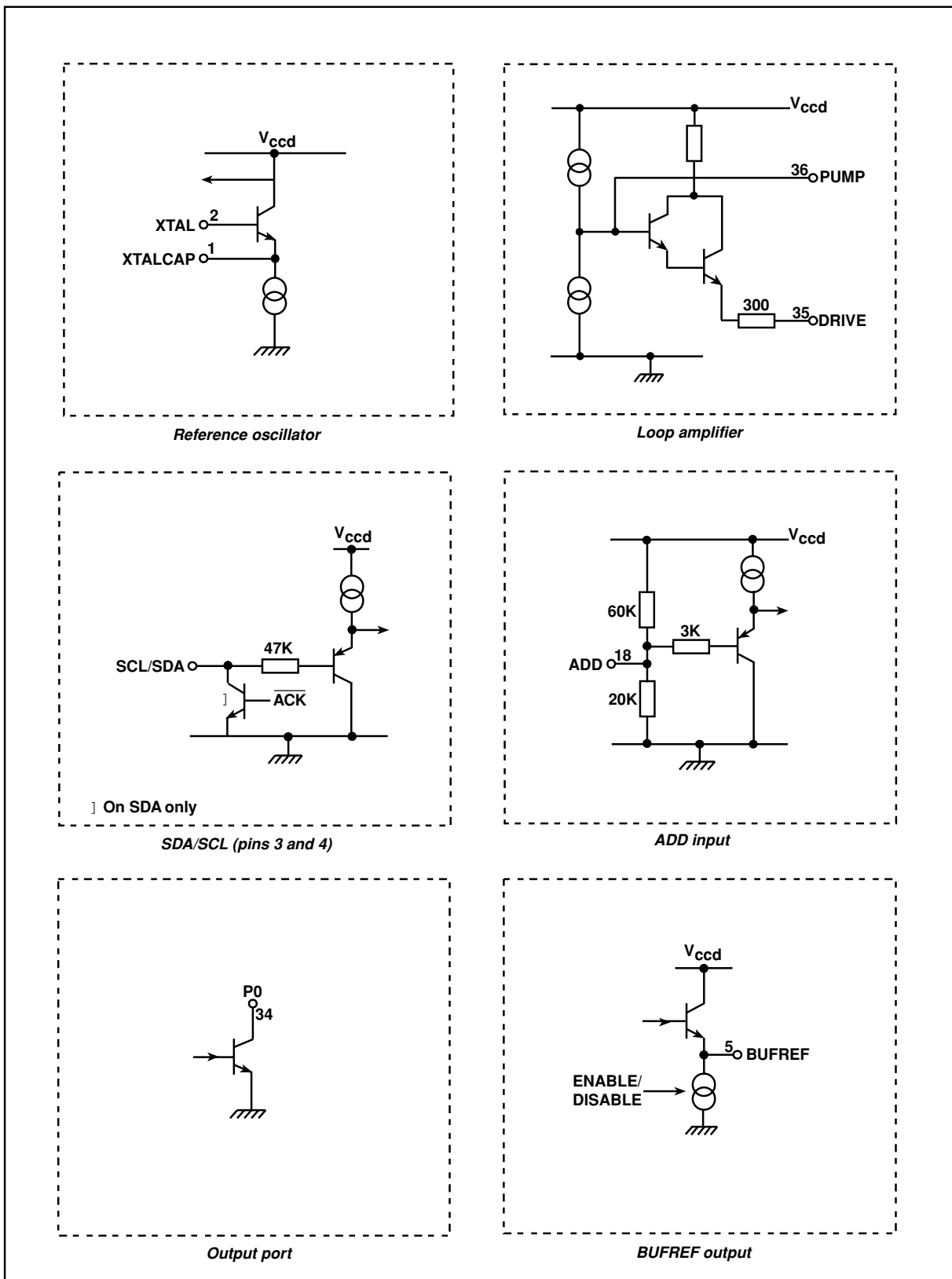


Figure 18. Input and output interface circuits (PLL section)



**Table 11. Absolute Maximum Ratings** (All voltages referred to Vee at 0V and Vcc = Vccd)

Characteristic	Min	Max	Units	Conditions
Supply voltage	-0.3	7	V	Vcc = Vee to 5.25V
SDA, SCL DC offsets	-0.3	6	V	
All I/O port DC offsets	-0.3	Vcc+0.3	V	
Port P0 current		10	mA	
Storage temperature	-55	150	°C	
Junction temperature		150	°C	
Package thermal resistance, chip to case		20	°C/W	
Package thermal resistance, chip to ambient		77	°C/W	
Power consumption at 5.25V		919	mW	Mil-std 883 method 3015 cat1
ESD protection	3.5		kV	

## SL1935 Demo Board

The demo board contains an SL1935 I<sup>2</sup>C bus controlled Zero IF tuner IC, plus all components necessary to demonstrate operation of the SL1935. The schematic and PCB layout of the board are shown in Figures 19, 20 and 21.

### Supplies

The board must be provided with the following supplies:

- 5V for the synthesiser section (5VD)
- 5V for the converter and baseband sections (5V)
- 30V for the varactor line (30V)

The supply connector is a 5 pin 0.1" pin header.  
The order of connections is 5V – GND – 30V – GND – 5V.

### I<sup>2</sup>C bus connections

The board is provided with a RJ11 I<sup>2</sup>C bus connector which feeds directly to the synthesiser. This connects to a standard 4 way cable.

## Operating instructions

### 1. Software.

Use the Zarlink Semiconductor synthesiser software. Pull down the 'Device' menu, then select the 'SL1935'. It is suggested that the charge pump is set to 130uA with a reference divider ratio of 32. These settings give a small loop bandwidth (i.e. 100's Hz), which allows detailed phase noise measurements of the oscillators to be taken if desired.

### 2. VCO control.

The two VCO's are selected by toggling the oscillator switch below the two oscillators on the main software block diagram. This switch programs bit VS of the I<sup>2</sup>C data (see Tables 8 and 9a to 9c).

VCOS oscillates at twice the LO frequency (lower band) and is then divided by two to provide the required LO frequency in the range 950MHz to 1500MHz (approximately).

VCOV oscillates at the LO frequency (upper band) in the range 1500MHz to 2150MHz (approximately).

### 3. Baseband path select.

The SL1935 has two filter paths selected by programming bit BS of the I<sup>2</sup>C data (see Tables 6 and 9a to 9c). The value of BS is changed by toggling the switch position to the left of 'Filter A' and 'Filter B' on the main software block diagram.

### 4. AGC control.

The conversion gain of the SL1935 is set by the voltage applied to the AGCCONT input. On the demo board this is controlled by the potential divider labelled 'AGC ADJ' which varies the AGCCONT input from 0V to Vcc.

**CAUTION:** Care should be taken to ensure the chip is powered ON if the board is modified to accept an external AGC input voltage. Damage to the device may result if this is not complied with as a result of the IC powering itself up via the AGCCONT input ESD protection diode. It is recommended that a low current limit is set on any external AGC voltage source used.

### 5. Free running the VCO's.

Select the required VCO as detailed in (2) above. Program an LO frequency which is above the maximum capability of the oscillator. 3GHz is suggested. Under this condition the varactor control voltage is pumped to its maximum value, ie to the top of the band. The oscillator frequency can now be manually tuned by varying the 30V supply.

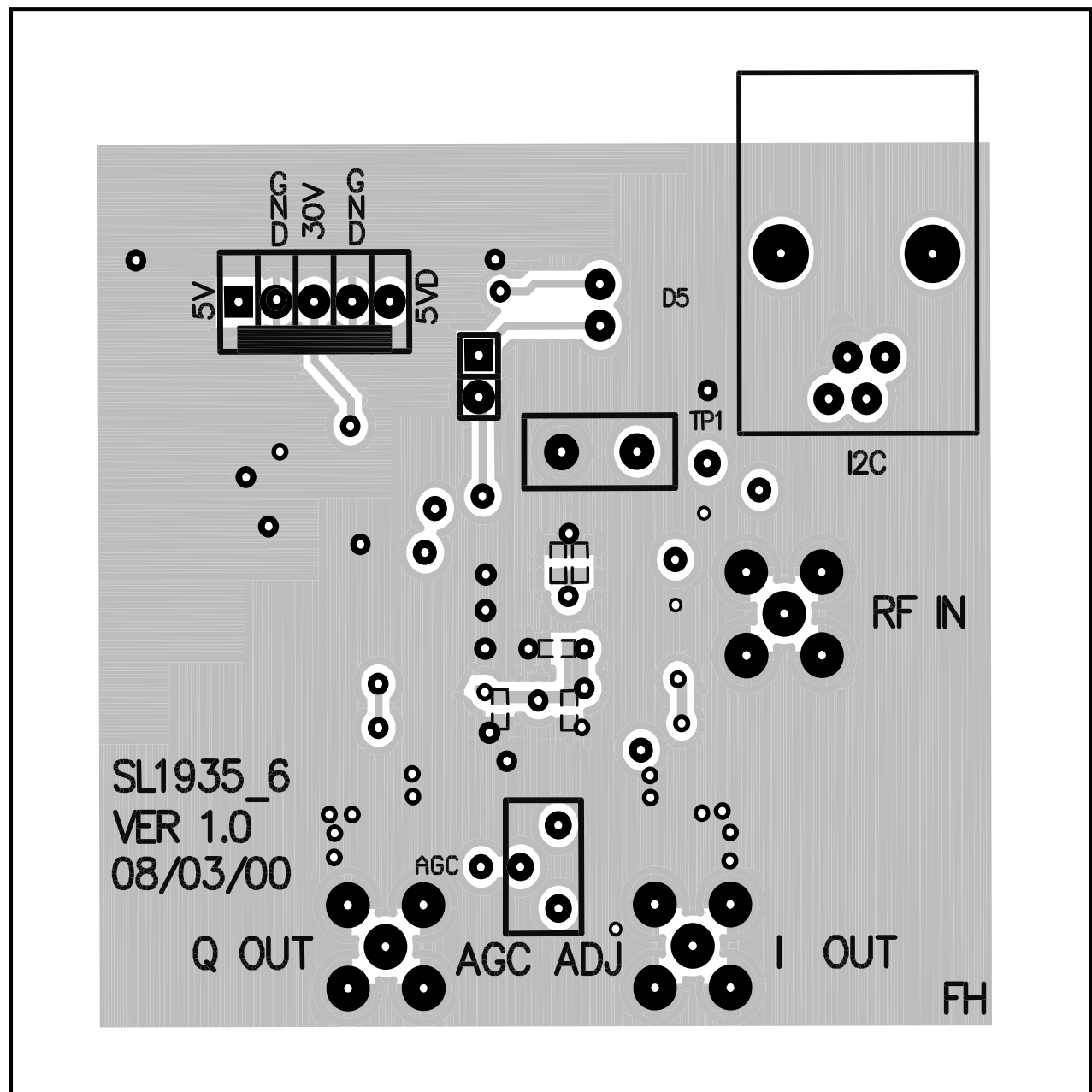


Figure 19. Top view

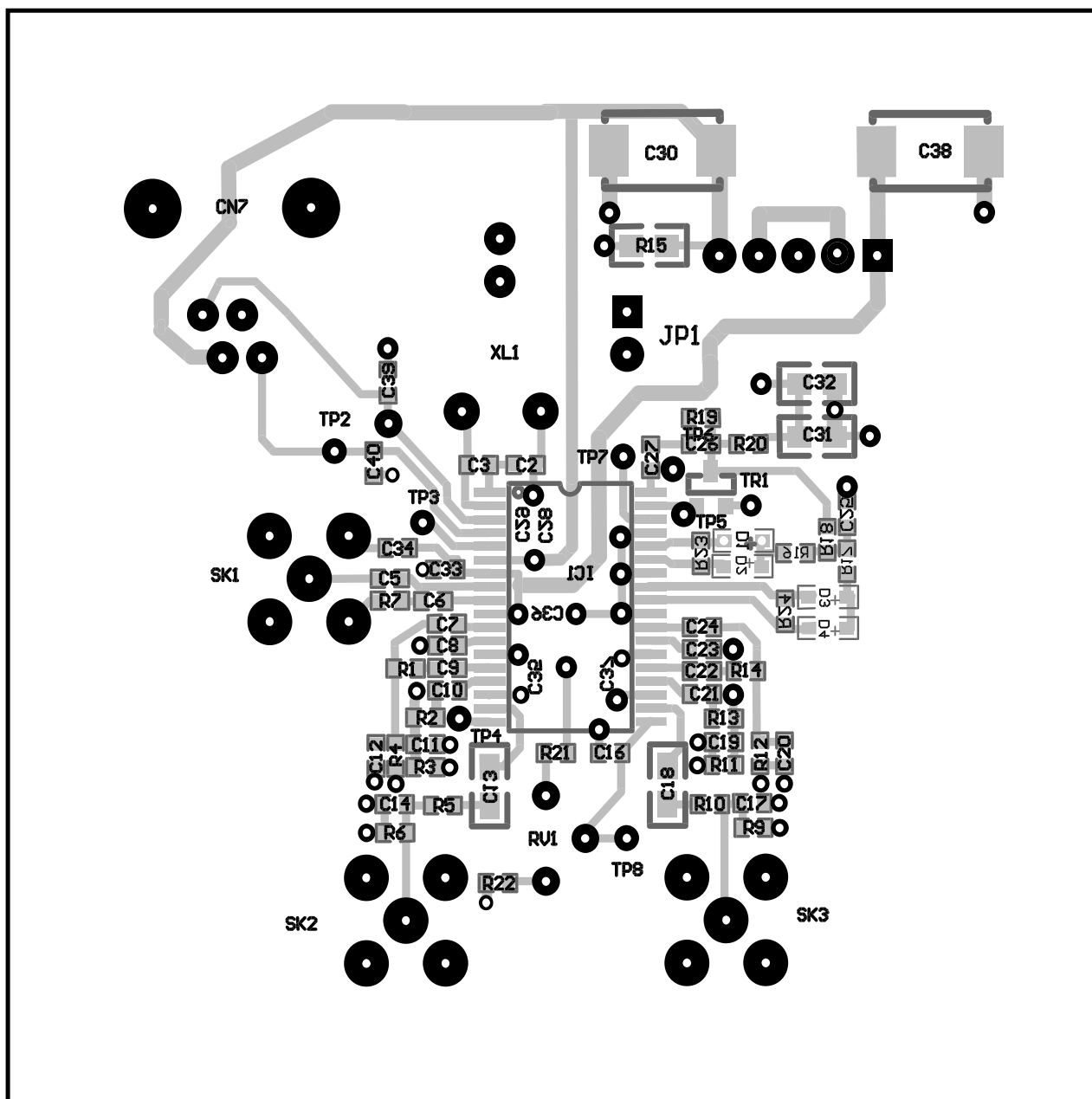


Figure 20. Bottom view

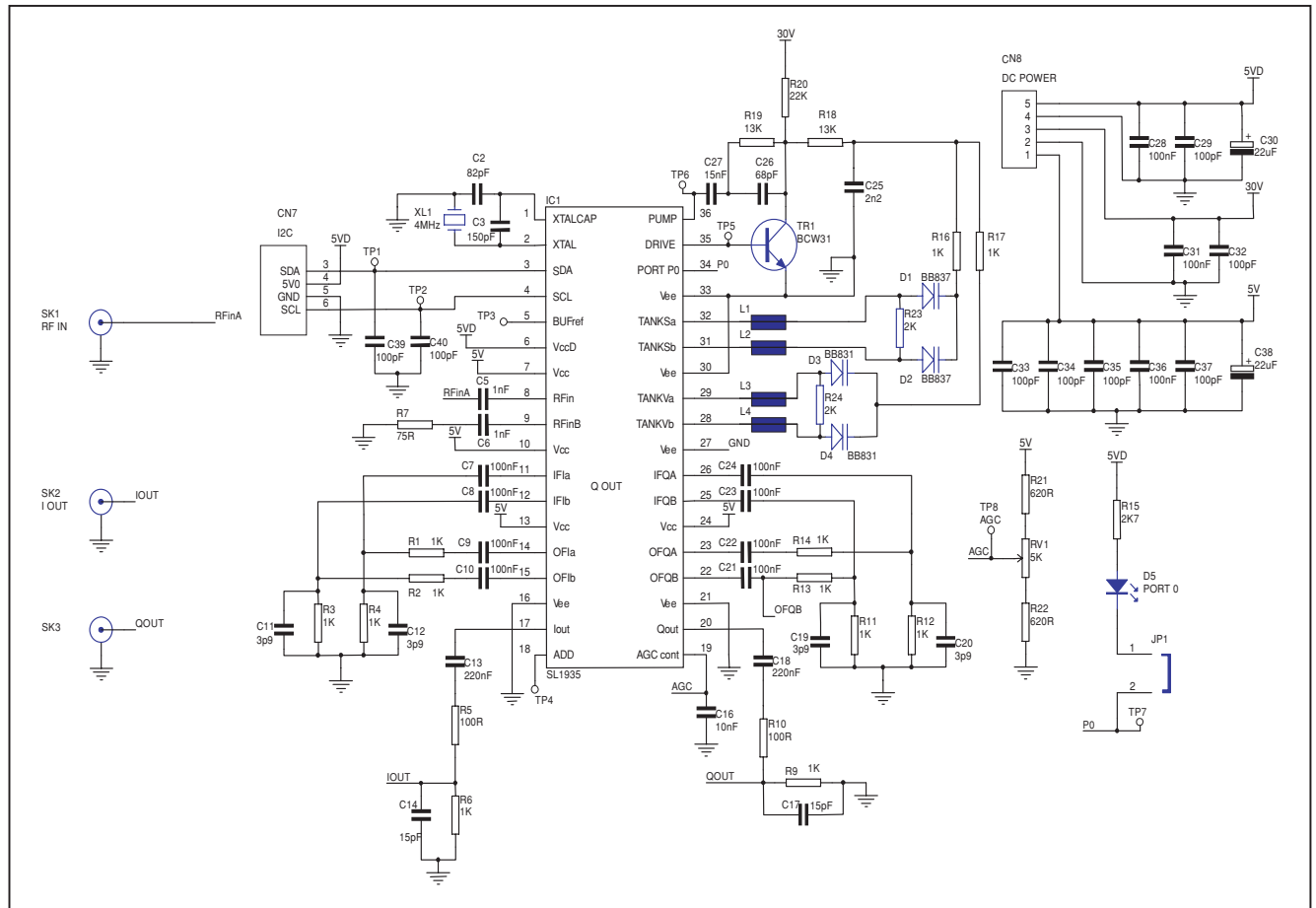
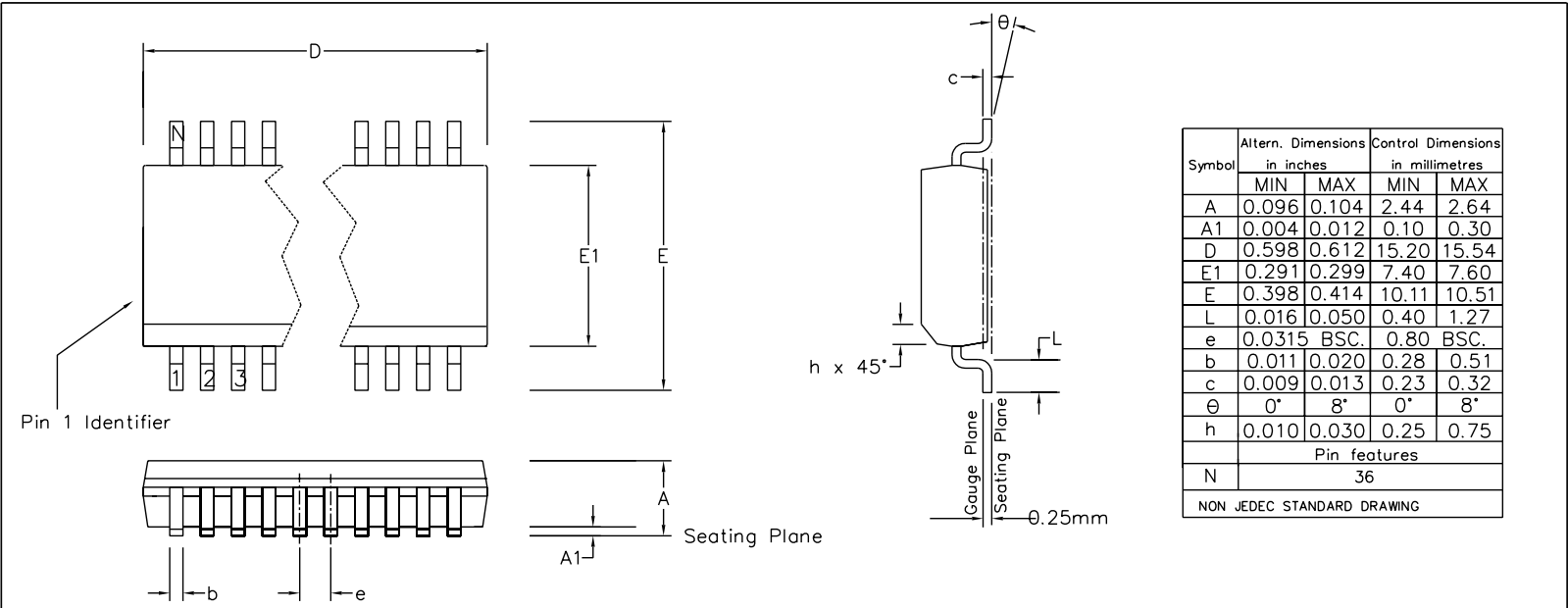


Figure 21.

Purchase of Zarlink Semiconductor I<sup>2</sup>C components conveys a licence under the Phillips I<sup>2</sup>C Patent rights to use these components in an I<sup>2</sup>C system, provided that the system conforms to the I<sup>2</sup>C Standard Specification as defined by Phillips.



- Notes:
1. Dimensioning and tolerancing per ANSI Y14.5M – 1982
  2. The chamfer on the body is optional. If it is not present, a visual index feature, e.g. a dot, must be located at pin 1 position.
  3. Controlling dimensions are in millimeters
  4. D & E1 do not include mould flash or protrusion. But do include mold mismatch.
  5. Dimension E1 does not include inter-lead flash or protrusion. These shall not exceed 0.010" per side.
  6. Dimension b does not include dambar protrusion/intrusion. Allowable dambar protrusion shall be 0.13mm total in excess of b dimension.
  7. Not to Scale

© Zarlink Semiconductor 2002 All rights reserved.					Package Code DD	
ISSUE	1	2	3		Previous package codes	Package Outline for 36 lead SSOP (7.5mm Body Width)
ACN	6741	207728	212423		NP / N	
DATE	14MAR95	5NOV99	22Mar02			GPD000008
APPRD.						





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